

Technical Data Data Sheet N1805, Rev. - **Green Products** 

# GBJ35005-GBJ3510

# Single-Phase 35.0A Glass Passivated Bridge Rectifier

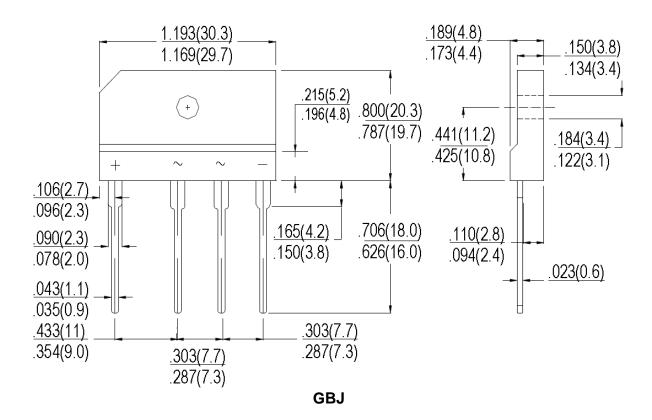
#### Features:

- Glass passivated die construction
- Low forward voltage drop
- High current capability
- High surge current capability
- Plastic material-UL flammability 94V-0

#### **Mechanical Data:**

- Case: GBJ, Molded plastic
- Terminals: Plated leads solderable per MIL-STD-202, Method 208
- Polarity: as marked on case
- Mounting Position: Any
- Lead Free: For RoHS / Lead Free Version

#### **Mechanical Dimensions: In Inches/mm**



# MARKING, MOLDING RESIN

Marking for Type Number, 1<sup>st</sup> row SSG YYWWL, 2<sup>nd</sup> row Type Number Where YY is the manufacture year WW is the manufacture week code L is the wafer's Lot Number

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**Maximum Ratings and Electrical Characteristics** Rating at 25°C ambient temperature unless otherwise specified. Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%

# **Maximum Ratings:**

Type Number	Symbol	GBJ 35005	GBJ 3501	GBJ 3502	GBJ 3504	GBJ 3506	GBJ 3508	GBJ 3510	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{DC} \end{array}$	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Average forward rectified output current (Note 1) @T <sub>A</sub> = 90°C	Io	35.0							Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	320							Α

# **Electrical Characteristics:**

Type Number	Symbol	GBJ 35005	GBJ 3501	GBJ 3502	GBJ 3504	GBJ 3506	GBJ 3508	GBJ 3510	Unit
Forward Voltage (per element)	$V_{FM}$	1.0 1.1							٧
Peak Reverse Current @T <sub>A</sub> = 25°C At Rated DC Blocking Voltage @T <sub>A</sub> = 125°C	I <sub>R</sub>	5.0 500						μA	
Typical Junction Capacitance(per leg) (Note 2)	CJ	75					pF		

**Thermal-Mechanical Specifications:** 

Type Number	Symbol	GBJ 35005	GBJ 3501	GBJ 3502	GBJ 3504	GBJ 3506	GBJ 3508	GBJ 3510	Unit
Between Junction and Ambient, Without heatsink	$R_{\theta JA}$	22							°C/ W
Between Junction and Case, Without heatsink	$R_{ heta JC}$	0.8							
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150							°C
Case Style	GBJ								

Note: 1. Mounted on glass epoxy PC board with 1.3mm<sup>2</sup> solder pad.

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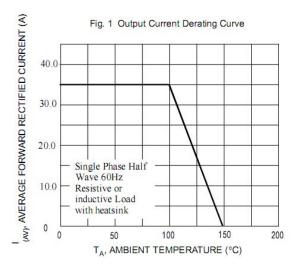
<sup>2.</sup> Measured at 1.0 MHz and applied reverse voltage of 5.0V D.C.

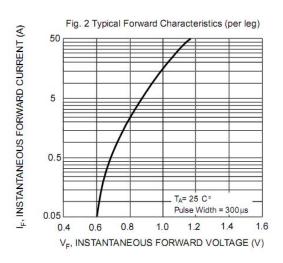


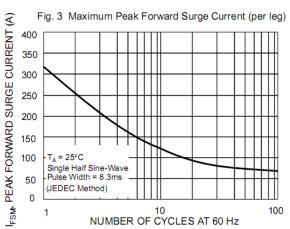
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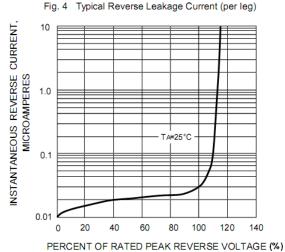
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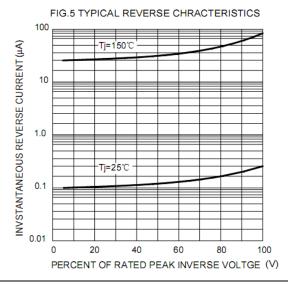
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